

HD74LV2G74A

Single D-type Flip Flops with Preset and Clear

REJ03D0097-0500

(Previous: ADE-205-346D)

Rev.5.00 Apr 07, 2006

Description

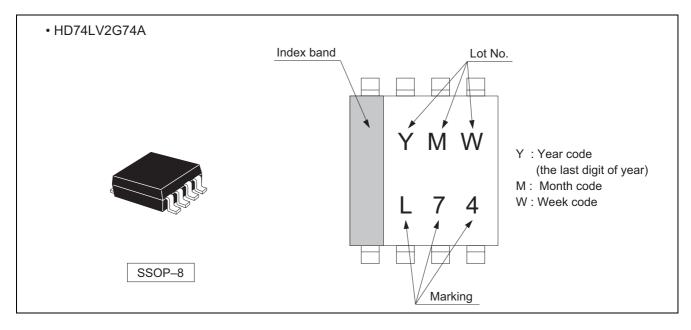
The HD74LV2G74A has independent data, preset, clear, and clock inputs Q and \overline{Q} outputs in an 8 pin package. The input data is transferred to the output at the rising edge of clock pulse CLK. Low voltage and high-speed operation is suitable for the battery powered products (e.g., notebook computers), and the low power consumption extends the battery life.

Features

- The basic gate function is lined up as Renesas uni logic series.
- Supplied on emboss taping for high-speed automatic mounting.
- Electrical characteristics equivalent to the HD74LV74A Supply voltage range: 1.65 to 5.5 V
 Operating temperature range: -40 to +85°C
- All inputs V_{IH} (Max.) = 5.5 V (@V_{CC} = 0 V to 5.5 V) All outputs V_{O} (Max.) = 5.5 V (@V_{CC} = 0 V)
- Output current ± 6 mA (@V_{CC} = 3.0 V to 3.6 V), ± 12 mA (@V_{CC} = 4.5 V to 5.5 V)
- All the logical input has hysteresis voltage for the slow transition.
- Ordering Information

Part Name	Package Type	Package Code (Previous code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LV2G74AUSE	•	PVSP0008KA-A (TTP-8DBV)	US	E (3,000 pcs / Reel)

Outline and Article Indication



www.DaFaunctionmTable

	Inp	uts		Outputs			
PRE	CLR	CLK	D	Q	Q		
L	Н	X	X	Н	L		
Н	L	X	X	L	Н		
L	L	X	X	H *1	H *1		
Н	Н	1	Н	Н	L		
Н	Н	1	L	L	Н		
Н	Н	\	Х	Q_0	\overline{Q}_0		

H : High level L : Low level

X : Immaterial

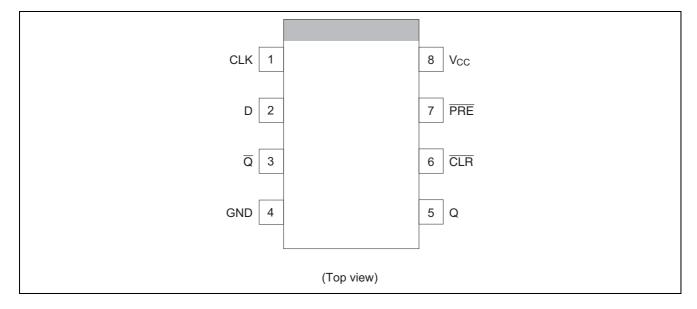
↑: Low to high transition

 \downarrow : High to low transition

Q₀: The level of Q immediately before the input conditions shown in the above table are determined.

Note: 1. Q and \overline{Q} will remain high as long as preset and clear are low, but Q and \overline{Q} are unpredictable, if preset and clear go high simultaneously.

Pin Arrangement



www.DaAbsolutenMaximum Ratings

Item	Symbol	Ratings	Unit	Test Conditions
Supply voltage range	V _{CC}	-0.5 to 7.0	V	
Input voltage range *1	Vı	-0.5 to 7.0	V	
Output voltage range *1, 2	Vo	-0.5 to V_{CC} + 0.5	V	Output : H or L
		-0.5 to 7.0		V _{CC} : OFF
Input clamp current	I _{IK}	-20	mA	V _I < 0
Output clamp current	I _{OK}	±50	mA	$V_O < 0$ or $V_O > V_{CC}$
Continuous output current	I _O	±25	mA	$V_O = 0$ to V_{CC}
Continuous current through V _{CC} or GND	I _{CC} or I _{GND}	±50	mA	
Maximum power dissipation	P _T	200	mW	
at Ta = 25°C (in still air) *3				
Storage temperature	Tstg	-65 to 150	°C	

Notes: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore no two of which may be realized at the same time.

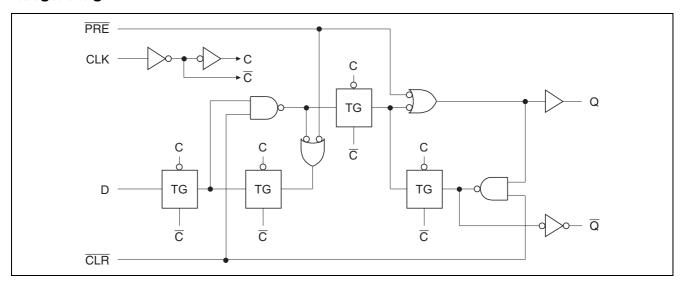
- 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- 2. This value is limited to 5.5 V maximum.
- 3. The maximum package power dissipation was calculated using a junction temperature of 150°C.

Recommended Operating Conditions

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	V _{CC}	1.65	5.5	V	
Input voltage range	Vı	0	5.5	V	
Output voltage range	Vo	0	V _{CC}	V	
Output current	I _{OL}	_	1	mA	V _{CC} = 1.65 to 1.95 V
		_	2		$V_{CC} = 2.3 \text{ to } 2.7 \text{ V}$
		_	6		$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$
		_	12		V _{CC} = 4.5 to 5.5 V
	I _{OH}	_	-1		V _{CC} = 1.65 to 1.95 V
		_	-2		$V_{CC} = 2.3 \text{ to } 2.7 \text{ V}$
		_	-6		$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$
		_	-12		V _{CC} = 4.5 to 5.5 V
Input transition rise or fall rate	Δt / Δν	0	300	ns / V	V _{CC} = 1.65 to 1.95 V
		0	200		$V_{CC} = 2.3 \text{ to } 2.7 \text{ V}$
		0	100		V _{CC} = 3.0 to 3.6 V
		0	20		V _{CC} = 4.5 to 5.5 V
Operating free-air temperature	Ta	-40	85	°C	

Note: Unused or floating inputs must be held high or low.

www.Daleogic.Diagram



Electrical Characteristics

Ta = -40 to $85^{\circ}C$

Item	Symbol	V _{CC} (V) *	Min	Тур	Max	Unit	Test condition
Input voltage	V _{IH}	1.65 to 1.95	V _{CC} ×0.75		_	V	
		2.3 to 2.7	V _{CC} ×0.7		_		
		3.0 to 3.6	V _{CC} ×0.7	_	_		
		4.5 to 5.5	V _{CC} ×0.7	_	_		
	V _{IL}	1.65 to 1.95	_	_	V _{CC} ×0.25		
		2.3 to 2.7	_	_	V _{CC} ×0.3		
		3.0 to 3.6	_	_	V _{CC} ×0.3		
		4.5 to 5.5	_	_	V _{CC} ×0.3		
Hysteresis voltage	V _H	1.8	_	0.25	_	V	$V_T^+ - V_T^-$
		2.5	_	0.30	_		
		3.3	_	0.35	_		
		5.0	_	0.45	_		
Output voltage	V _{OH}	Min to Max	V _{CC} -0.1	_	_	V	$I_{OH} = -50 \mu A$
		1.65	1.4	_	_		$I_{OH} = -1 \text{ mA}$
		2.3	2.0	_	_		$I_{OH} = -2 \text{ mA}$
		3.0	2.48	_	_		$I_{OH} = -6 \text{ mA}$
		4.5	3.8	_	_		I _{OH} = -12 mA
	V _{OL}	Min to Max	_	_	0.1		$I_{OL} = 50 \mu A$
		1.65	_	_	0.3		I _{OL} = 1 mA
		2.3	_	_	0.4		$I_{OL} = 2 \text{ mA}$
		3.0	_	_	0.44		$I_{OL} = 6 \text{ mA}$
		4.5	_	_	0.55		$I_{OL} = 12 \text{ mA}$
Input current	I _{IN}	0 to 5.5	_	_	±1	μΑ	$V_{IN} = 5.5 \text{ V or GND}$
Quiescent supply current	I _{CC}	5.5	_	_	10	μΑ	$V_{IN} = V_{CC}$ or GND, $I_O = 0$
Output leakage current	I _{OFF}	0	_	_	5	μΑ	V_{IN} or $V_O = 0$ to 5.5 V
Input capacitance	C _{IN}	3.3	_	2.5	_	pF	$V_{IN} = V_{CC}$ or GND

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

www.DaSwitching Characteristics

 $V_{CC}=1.8\pm0.15~V$

Item	Symbol		$T_a = 25^{\circ}C$			to 85°C	Unit	Test	FROM	ТО
item	Symbol	Min	Тур	Max	Min	Max	Unit	Conditions	(Input)	(Output)
Maximum clock	f _{max}	30	60	_	20	_	MHz	$C_L = 15 pF$		
frequency		20	40	_	15	_		C _L = 50 pF]	
Propagation	t _{PLH}	_	16.3	27.0	1.0	29.0	ns	$C_L = 15 pF$	PRE/CLR	Q or Q
delay time	t _{PHL}	_	17.9	29.0	1.0	32.0			CLK	
		_	21.6	34.0	1.0	36.5		C _L = 50 pF	PRE/CLR	Q or $\overline{\mathbb{Q}}$
		_	24.5	39.5	1.0	42.5			CLK	
Setup time	t _{su}	13.0	_	_	14.0	_	ns		D	
		9.0	_	_	9.0	_			PRE or CLR	inactive
Hold time	t _h	0.5	_	_	0.5	_	ns			
Pulse width	t _w	12.0	_	_	13.0	_	ns		PRE or CLR	"L"
		12.0	_	_	13.0	_			CLK "H" or "	"

 $V_{CC}=2.5\pm0.2~V$

Item	Symbol		T _a = 25°C		$T_a = -40$	to 85°C	Unit	Test	FROM	ТО
item	Syllibol	Min	Тур	Max	Min	Max	Onit	Conditions	(Input)	(Output)
Maximum clock	f _{max}	50	100	_	40	_	MHz	C _L = 15 pF		
frequency		30	70	_	25	_		C _L = 50 pF		
Propagation	t _{PLH}	_	9.8	14.8	1.0	17.0	ns	C _L = 15 pF	PRE/CLR	Q or \overline{Q}
delay time	t _{PHL}	_	11.1	16.4	1.0	19.0			CLK	
		_	13.0	17.4	1.0	20.0		C _L = 50 pF	PRE/CLR	Q or \overline{Q}
		_	14.2	20.0	1.0	23.0			CLK	
Setup time	t _{su}	8.0	_	_	9.0	_	ns		D	
		7.0	_	_	7.0	_			PRE or CLR	inactive
Hold time	t _h	0.5	_	_	0.5	_	ns			
Pulse width	t _w	8.0	_	_	9.0	_	ns		PRE or CLR	"L"
		8.0	_	_	9.0	_			CLK "H" or "L	

 $V_{CC} = 3.3 \pm 0.3 \text{ V}$

Item	Symbol		T _a = 25°C	;	$T_a = -40$	to 85°C	Unit	Test	FROM	ТО
item	Syllibol	Min	Тур	Max	Min	Max	Oilit	Conditions	(Input)	(Output)
Maximum clock	f _{max}	80	140	_	70	_	MHz	$C_L = 15 pF$		
frequency		50	90	_	45	_		C _L = 50 pF		
Propagation	t _{PLH}	_	6.9	12.3	1.0	14.5	ns	$C_L = 15 pF$	PRE/CLR	Q or \overline{Q}
delay time	t _{PHL}	_	7.9	11.9	1.0	14.0			CLK	
		_	9.2	15.8	1.0	18.0		C _L = 50 pF	PRE/CLR	Q or Q
		_	10.2	15.4	1.0	17.5			CLK	
Setup time	t _{su}	6.0	_	_	7.0	_	ns		D	
		5.0	_	_	5.0	_			PRE or CLR	inactive
Hold time	t _h	0.5	_	_	0.5	_	ns			
Pulse width	t _w	6.0	_	_	7.0	_	ns		PRE or CLR	"L"
		6.0	_	_	7.0	_			CLK "H" or "l	"

www.DataSheet4U.com $V_{CC} = 5.0 \pm 0.5 \ V$

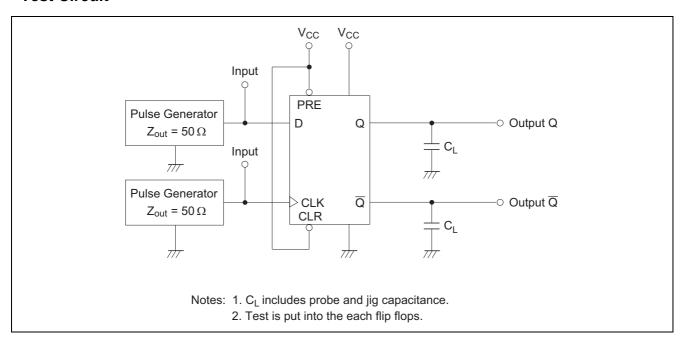
Item	Symbol	T _a = 25°C			$T_a = -40$	to 85°C	Unit	Test	FROM	ТО
item	Syllibol	Min	Тур	Max	Min	Max	Onit	Conditions	(Input)	(Output)
Maximum clock	f _{max}	130	180	_	110	_	MHz	$C_L = 15 pF$		
frequency		90	140	_	75	_		C _L = 50 pF		
Propagation	t _{PLH}	_	5.0	7.7	1.0	9.0	ns	$C_L = 15 pF$	PRE/CLR	Q or \overline{Q}
delay time	t_{PHL}	_	5.6	7.3	1.0	8.5			CLK	
		_	6.6	9.7	1.0	11.0		$C_L = 50 pF$	PRE/CLR	Q or $\overline{\mathbb{Q}}$
		_	7.2	9.3	1.0	10.5			CLK	
Setup time	t _{su}	5.0	_	_	5.0	_	ns		D	
		3.0	_	_	3.0	_			PRE or CLR	inactive
Hold time	t _h	0.5	_	_	0.5	_	ns			
Pulse width	t _w	5.0	_	_	5.0	_	ns		PRE or CLR	"L"
		5.0	_	_	5.0	_			CLK "H" or "l	"

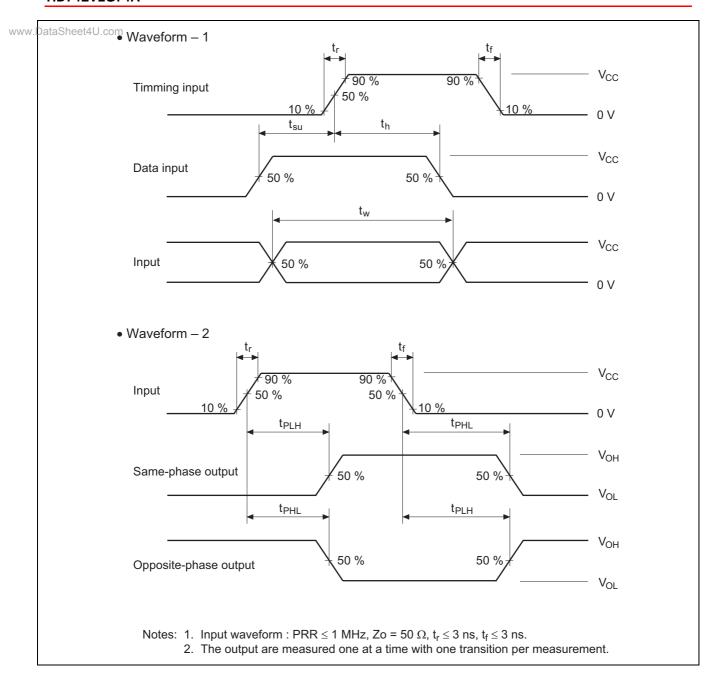
Operating Characteristics

 $C_L = 50 \text{ pF}$

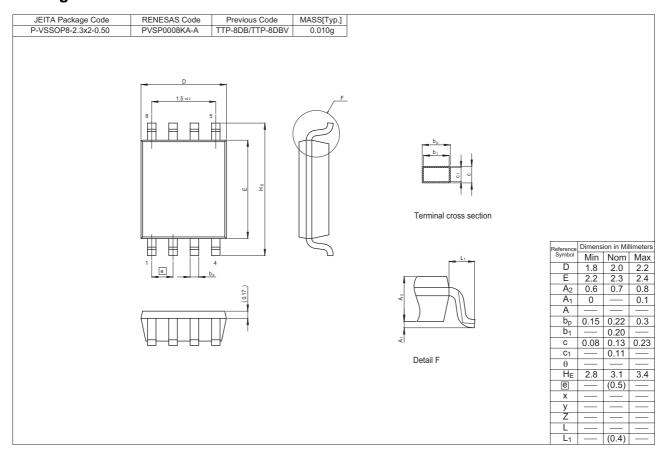
Item	Symbol	V _{cc} (V)		T _a = 25°C		Unit	Test Conditions	
item	Symbol		Min	Тур	Max	Offic		
Power dissipation	C _{PD}	3.3	_	13.0	_	pF	f = 10 MHz	
capacitance		5.0	_	14.0	_			

Test Circuit





www.Dapackage Dimensions



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